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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/501,351	07/14/2004	Seiji Samukawa	SHIG CPTA0502FE	7535
27667 7590 02/06/2008 HAYES SOLOWAY P.C. 3450 E. SUNRISE DRIVE, SUITE 140 TUCSON, AZ 85718			EXAMINER DHINGRA, RAKESH KUMAR	
			ART UNIT 1792	PAPER NUMBER
			MAIL DATE 02/06/2008	DELIVERY MODE PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No. 10/501,351	Applicant(s) SAMUKAWA ET AL.	
	Examiner RAKESH K. DHINGRA	Art Unit 1792	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 03 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 03 December 2007.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1,2 and 5-13 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1,2 and 5-13 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 26 December 2006 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 12/3/07 has been entered.

Response to Arguments

Applicant's arguments with respect to claims 1-2, 5-12 have been considered but are moot in view of the new ground(s) of rejection as explained hereunder.

Applicant has amended claims 1, 2 by adding new limitations (for example in claim 1 – “the plurality of electrodes formed in a zigzag linear configuration and having pores of predetermined size formed therein” and “sensor formed at the bottom of each sensor section”). Further applicant has added new claim 13.

Accordingly claims 1, 2, 5-13 are now pending and active.

Responding to applicant's argument that none of the prior art teaches the limitations of amended claim 1, examiner states that Loewenhardt et al teaches plurality of electrodes 206, 212, 218 having pores of predetermined size (mesh type electrodes), as per claim limitation. Further, Ma et al teach a sensor 116 formed at the bottom of the sensor section 110 and connected to probe pad 144. As regards the electrodes having a zigzag shape, absent any disclosed criticality in applicant's disclosure, shape is considered a matter of choice. Thus, Ma et al in view of Smesny et al and Loewenhardt et al teach all limitations of amended claim 1 as explained below. Accordingly claims 1, 5, 6, 9 and 12 have been rejected under 35

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USC 103 (a) as explained below. Balance claims 2, 7, 8, 10, 11 and new claim 13 have also been rejected under 35 USC 103 (a) as explained below.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1, 5, 6, 9 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ma et al (US Patent No. 6,576,922) in view of Smesny et al (US Patent No. 5,444,637) and Loewenhardt et al (US Patent No. 5,451,784).

Regarding Claim 1: Ma et al teach an apparatus (Figures 2, 6, 9-13) comprising:
an on-wafer plasma monitoring apparatus 112 (Figure 2) comprising:
a ferroelectric (FE) capacitor 110 with antenna 114 (one or a plurality of sensor sections)
provided on a substrate 118 and includes a pattern portion, which is a plasma treatment target, and a plurality of electrodes 126, 122 with insulating film 124 between the electrodes, and where the uppermost

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electrode 126 has same potential as that of substrate 18 (through resistor 142, upper and lower vertical conductive portions 127, 128 and antenna 114 respectively). Ma et al also teach a sensor 116 formed at the bottom of the sensor section 110 and connected to probe pad 144 that can be formed through a patterned portion (e.g. Figs. 2, 6, 9-13 and col. 6, line 36 to col. 7, line 58).

Ma et al teach on-wafer sensors but do not explicitly teach said pattern portion, said plurality of electrodes formed in a zigzag shape and having pores of predetermined size, and also do not teach a power source unit and an I/O unit that inputs/outputs signals from to/outside and where the power source unit takes out power from plasma potential or takes out power from photo-electromotive force of a PLZT device.

Smesny et al teach a plasma sensing apparatus (Figures 1, 2) comprising:

A wafer 10 with plurality of sensors 12, a power source 16 that can use plasma photon energy and converts it to electrical energy, a signal acquisition and conditioning unit 18 with processor 20 (like an I/O unit) that receives/sends signals from outside (through external control circuit 22) [column 6, line 35 to column 7, line 50].

Therefore it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the plasma monitoring system with power source unit and I/O unit as taught by Smesny et al in the apparatus of Ma et al to enable operation of various sensors/other circuits on the wafer.

Ma et al in view of Smesny et al do not teach said pattern portion and the plurality of electrodes having pores of pre-determined size formed therein.

However providing opening (pores) in the electrodes that are used for monitoring ion energy is known in the art as per reference cited hereunder.

Loewenhardt et al teach an apparatus for ion energy measurement during semiconductor wafer processing (Figs. 1, 2, 4, 5) comprising:

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a monitoring wafer 102 with ion energy analyzers 104, and pattern portion having layers of insulation 202, 208, 214 with apertures, plurality of electrodes 206, 212, 218 having pores of predetermined size (approx. 200 mils per inch) and where the measuring system enables to measure ion current and to obtain ion energy distribution (e.g. Figs. 1, 2, 4, 5 and col. 3, line 30 to col. 6, line 15).

It would have been obvious to one of ordinary skill in the art at the time of the invention to provide a measuring system with a pattern portion of sensor sections and pores in the electrodes as taught by Loewenhardt et al in the apparatus of Ma et al in view of Smesny et al to obtain accurate ion energy profile.

Further, though Ma et al in view of Smesny et al and Loewenhardt et al do not teach the electrodes having a zigzag shape, the same is a matter choice, absent any disclosed criticality.

In this connection courts have ruled:

It was held in re Dailey, 357 F.2d 669, 149 USPQ 47 (CCPA 1966) that the shape was a matter of choice which a person of ordinary skill in the art would have found obvious absent persuasive evidence that the particular shape was significant. (Also see MPEP 2144.04(d)).

Regarding Claims 5, 9: Smesny et al teach that the test wafer includes an input probe that can receive optically transmitted information (would include photon detector) [column 5, lines 1-22].

Regarding Claim 6: Loewenhardt et al teach that the apparatus (Figures 1, 2) includes a monitoring wafer 102 with ion energy analyzers 104 and where a collector electrode 200 is disposed at the bottom of the sensor section that measures ion current and enables to obtain ion energy distribution (column 3, line 30 to column 6, line 15).

Regarding Claim 12: Loewenhardt et al teach probes 106 that can measure ion current (Figure 2 and column 6, lines 1-15).

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Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ma et al (US Patent No. 6,576,922) in view of Smesny et al (US Patent No. 5,444,637) and Loewenhardt et al (US Patent No. 5,451,784) as applied to claims 1, 5, 6, 9, 12 and further in view of Ma (US Patent No. 6,673,636).

Regarding Claim 2: Ma et al ('922) in view of Smesny et al and Loewenhardt et al teach all limitations of the claim including plurality of electrode separated by insulation layers, but do not teach that plurality of electrodes of sensor section are aluminum electrodes and space between each of aluminum electrodes is insulated by gamma-Al₂O₃.

Ma ('636) teach an apparatus (Figures 5-7) for real time measurement of plasma parameters and comprising of a silicon substrate 601 provided with an aluminum electrode 604 in a patterned portion of a resist layer and where there is an insulator layer 603 of Aluminum oxide (Al₂O₃) provided between substrate and the electrode 604. Further, it is known in the art to use anodization, that is, aluminum oxide (gamma-Al₂O₃) as insulating layer over silicon wafers (column 3, line 1 to column 4, line 20 and column 5, line 1 to column 6, line 65).

Therefore it would have been obvious to one of ordinary skill in the art at the time of the invention to use aluminum as electrode material and aluminum oxide as insulator material as taught by Ma et al ('636) in the apparatus of Ma et al ('922) in view of Smesny et al and Loewenhardt et al, due to aluminum being a known good conductor suitable for plasma processing environment and aluminum oxide having better anti-corrosion properties than other comparable materials like SiO₂.

Claims 7, 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ma et al (US Patent No. 6,576,922) in view of Smesny et al (US Patent No. 5,444,637) and Loewenhardt et al (US Patent No. 5,451,784) as applied to claims 1, 5, 6, 9, 12 and further in view of Toyoda (US Patent No. 6,462,328).

Regarding Claim 7: Ma et al in view of Smesny et al and Loewenhardt et al teach all limitations of the claim including use of photon detectors as sensors, but do not teach photo detector detects light made incident into a pattern by photo-induced current generated in an insulating film.

Toyoda teaches an apparatus (Figure 5) that includes photosensors Dr, Dc that detect light after passing through silicon oxide (insulating film) 40, 38, 25 and where the electric current is proportional to the amount of incident light (column 5, lines 38-58).

It would have been obvious to one of ordinary skill in the art at the time of the invention to manufacture photo-detection sensor as taught by Toyoda in the apparatus of Ma et al in view of Smesny et al and Loewenhardt et al to obtain accurate an accurate measurement of light energy.

Regarding Claim 8: Toyoda teaches that photo sensor includes an aluminum film (metal film) 42a formed on the oxide film 40 that helps to avoid scattering light reaching the light receiving sensor portions. Further, the dependence of light detected on the work function difference is a functional aspect that would depend upon the type of materials selected for the metallic and the oxide coatings and other related parameters.

Claims 10, 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ma et al (US Patent No. 6,576,922) in view of Smesny et al (US Patent No. 5,444,637) and Loewenhardt et al (US Patent No. 5,451,784) as applied to claims 1, 5, 6, 9, 12 and further in view of Pinnaduwege (US Patent No. 5,896,196)

Regarding Claims 10,11: Ma et al in view of Smesny et al and Loewenhardt et al teach all limitations of the claim including use of spectrophotometer sensors, that incorporate specific bandwidth optical filters using chip fabrication techniques for measuring plasma parameters like ion current flux, charge particle (like ions) density etc.

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Ma et al in view of Smesny et al and Loewenhardt et al do not explicitly teach use of spectrophotometric sensors for identification of radicals and ions by collision between ions/radicals and electrons generated by an electron gun.

Pinnaduwege teaches an apparatus (Figures 1-3) where a glow discharge apparatus 10 has an analysis region 22 in which an electron beam is introduced from electrode 14 (electron gun) and positive and negative ions can be identified using optical spectrometer 54. Pinnaduwege also teaches that typically in prior art an electron gun is used as a source of electrons that collide with gas particles (column 1, line 10 to column 32, line 30).

Therefore it would have been obvious to one of ordinary skill in the art at the time of the invention to use ion radical identification techniques as taught by Pinnaduwege in the apparatus of Ma et al in view of Smesny et al and Loewenhardt et al to enable accurately identify ions and radicals using emission spectro-photometric techniques.

Claim 13 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ma et al (US Patent No. 6,576,922) in view of Smesny et al (US Patent No. 5,444,637), Loewenhardt et al (US Patent No. 5,451,784) and Ma (US Patent No. 6,673,636) as applied to claim 2 and further in view of Johnson et al (US PG PUB No. 2004/0021094).

Regarding Claim 13: Ma et al ('922) in view of Smesny et al, Loewenhardt et al and Ma ('636) teach all limitations of the claim except that side surface of aluminum electrode is covered with a thin oxide film.

Johnson et al teach an apparatus (Figures 2-5) that includes a monitoring wafer 12 with a substrate 20 that has aluminum ion current collectors (electrodes) 26 that have an anodized (covered with thin oxide film) cylindrical surface (e.g. Figs. 2-5 and para. 0039, 0040).

It would have been obvious to one of ordinary skill in the art at the time of the invention to use aluminum electrodes with side surface covered with oxide film as taught by Johnson et al in the apparatus

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of Ma et al ('922) in view of Smesny et al, Loewenhardt et al and Ma et al ('636) to insulate the electrode from the adjoining structures (like wall of enclosing wafer 10 or adjoining electrodes).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to RAKESH K. DHINGRA whose telephone number is (571)272-5959. The examiner can normally be reached on 8:30 -6:00 (Monday - Friday).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on (571)-272-1435. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.



Rakesh K. Dhingra



Karla Moore
Primary Examiner
Art Unit 1763